FAIRCHILD SEMICONDUCTOR®

August 2011

FDD24AN06LA0_F085

N-Channel Logic Level PowerTrench® MOSFET
60V, 36A, 24mΩ

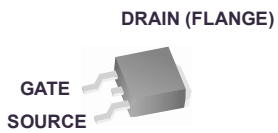
Features

- $r_{DS(ON)}$ = 20mΩ (Typ.), V_{GS} = 5V, I_D = 36A
- Q_g(tot) = 16nC (Typ.), V_{GS} = 5V
- Low Miller Charge
- Low Q_{RR} Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant

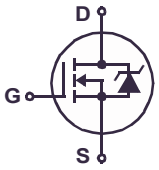
Formerly developmental type 83547

Applications

- Motor / Body Load Control
- ABS Systems
- Powertrain Management
- Injection Systems
- DC-DC converters and Off-line UPS
- Distributed Power Architectures and VRMs
- Primary Switch for 12V and 24V systems



TO-252AA
FDD SERIES



MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DSS}	Drain to Source Voltage	60	V
V_{GS}	Gate to Source Voltage	±20	V
I_D	Drain Current Continuous (T_C = 25°C, V_{GS} = 10V)	40	A
	Continuous (T_C = 25°C, V_{GS} = 5V)	36	A
	Continuous (T_C = 100°C, V_{GS} = 5V)	25	A
	Continuous (T_A = 25°C, V_{GS} = 5V, $R_{\theta JA}$ = 52°C/W)	7.1	A
	Pulsed	Figure 4	A
E_{AS}	Single Pulse Avalanche Energy (Note 1)	32	mJ
P_D	Power dissipation	75	W
	Derate above 25°C	0.5	W/°C
T_J, T_{STG}	Operating and Storage Temperature	-55 to 175	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case TO-252	2.0	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-252	100	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-252, 1in^2 copper pad area	52	°C/W

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/

Reliability data can be found at: http://www.fairchildsemi.com/products/discrete/reliability/index.html.

All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

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Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD24AN06LA0	FDD24AN06LA0	TO-252AA	330mm	16mm	2500 units

Electrical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
B_{VDSS}	Drain to Source Breakdown Voltage	I_D = 250µA, V_{GS} = 0V	60	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 50V, V_{GS} = 0V	-	-	1	µA
		V_{DS} = 50V, V_{GS} = 0V, T_C = 150°C	-	-	250	
I_{GSS}	Gate to Source Leakage Current	V_{GS} = ±20V	-	-	±100	nA
On Characteristics						
$V_{GS(TH)}$	Gate to Source Threshold Voltage	V_{GS} = V_{DS}, I_D = 250µA	1	-	2	V
$r_{DS(ON)}$	Drain to Source On Resistance	I_D = 40A, V_{GS} = 10V	-	0.016	0.019	Ω
		I_D = 36A, V_{GS} = 5V	-	0.020	0.024	
		I_D = 36A, V_{GS} = 5V, T_J = 175°C	-	0.047	0.056	
Dynamic Characteristics						
C_{ISS}	Input Capacitance	V_{DS} = 25V, V_{GS} = 0V, f = 1MHz	-	1850	-	pF
C_{OSS}	Output Capacitance		-	180	-	pF
C_{RSS}	Reverse Transfer Capacitance		-	75	-	pF
$Q_{g(TOT)}$	Total Gate Charge at 5V	V_{GS} = 0V to 5V, V_{DD} = 30V, I_D = 36A, I_g = 1.0mA		16	21	nC
$Q_{g(TH)}$	Threshold Gate Charge	V_{GS} = 0V to 1V, V_{DD} = 30V, I_D = 36A, I_g = 1.0mA	-	1.8	2.4	nC
Q_{gs}	Gate to Source Gate Charge	V_{DD} = 30V, I_D = 36A, I_g = 1.0mA	-	6.3	-	nC
Q_{gs2}	Gate Charge Threshold to Plateau	V_{DD} = 30V, I_D = 36A, I_g = 1.0mA	-	4.5	-	nC
Q_{gd}	Gate to Drain “Miller” Charge	V_{DD} = 30V, I_D = 36A, I_g = 1.0mA	-	5.0	-	nC
Switching Characteristics (V_{GS} = 5V)						
t_{ON}	Turn-On Time	V_{DD} = 30V, I_D = 36A, V_{GS} = 5V, R_{GS} = 9.1Ω	-	-	195	ns
$t_{d(ON)}$	Turn-On Delay Time		-	12	-	ns
t_r	Rise Time		-	118	-	ns
$t_{d(OFF)}$	Turn-Off Delay Time		-	26	-	ns
t_f	Fall Time		-	41	-	ns
t_{OFF}	Turn-Off Time		-	-	101	ns
Drain-Source Diode Characteristics						
V_{SD}	Source to Drain Diode Voltage	I_{SD} = 36A	-	-	1.25	V
		I_{SD} = 18A	-	-	1.0	V
t_{rr}	Reverse Recovery Time	I_{SD} = 36A, dI_{SD}/dt = 100A/µs	-	-	34	ns
Q_{RR}	Reverse Recovered Charge	I_{SD} = 36A, dI_{SD}/dt = 100A/µs	-	-	30	nC

Notes:
1: Starting T_J = 25°C, L = 80µH, I_{AS} = 28A.

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Typical Characteristics T_C = 25°C unless otherwise noted

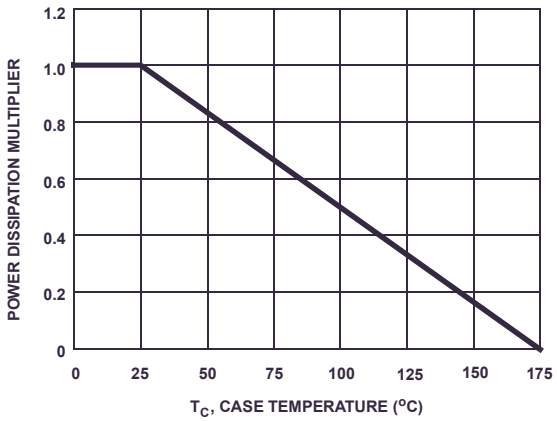


Figure 1. Normalized Power Dissipation vs Ambient Temperature

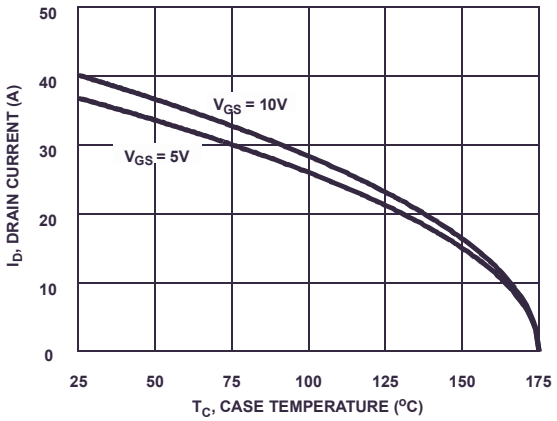


Figure 2. Maximum Continuous Drain Current vs Case Temperature

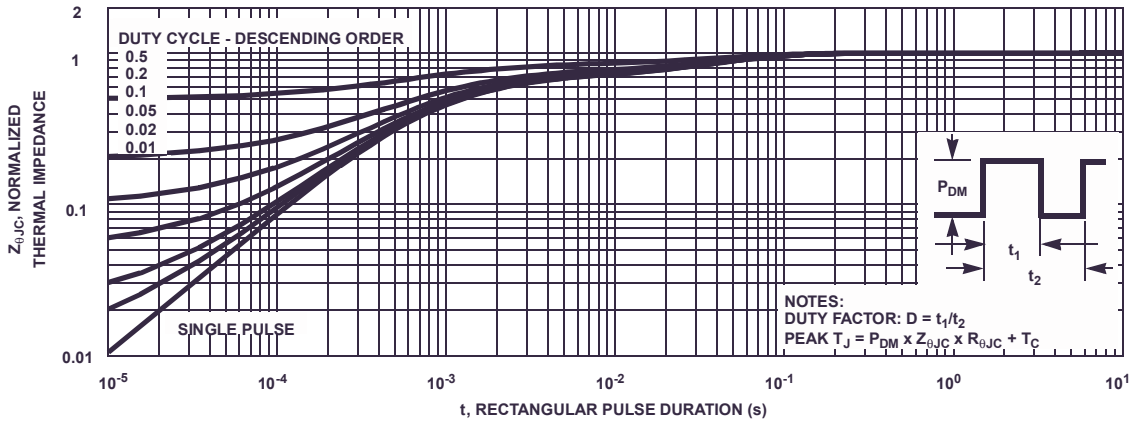


Figure 3. Normalized Maximum Transient Thermal Impedance

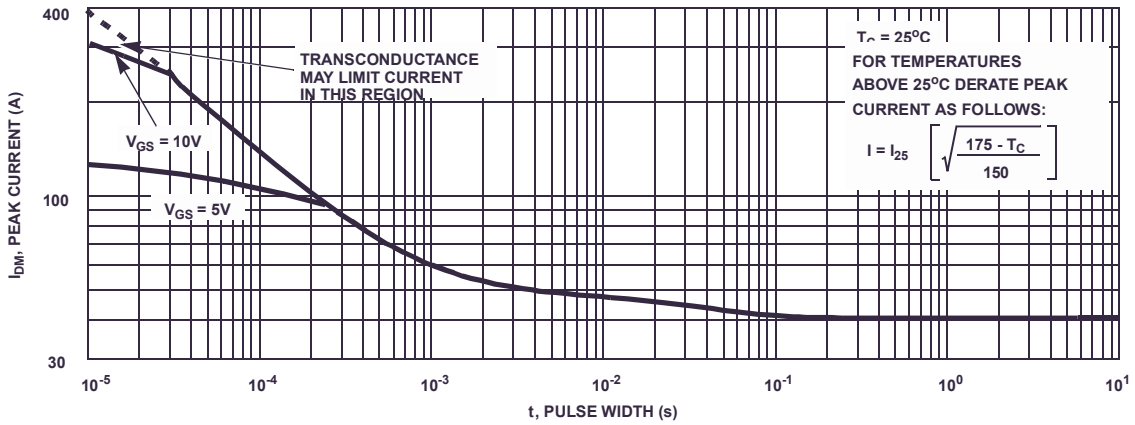


Figure 4. Peak Current Capability

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Typical Characteristics T_C = 25°C unless otherwise noted

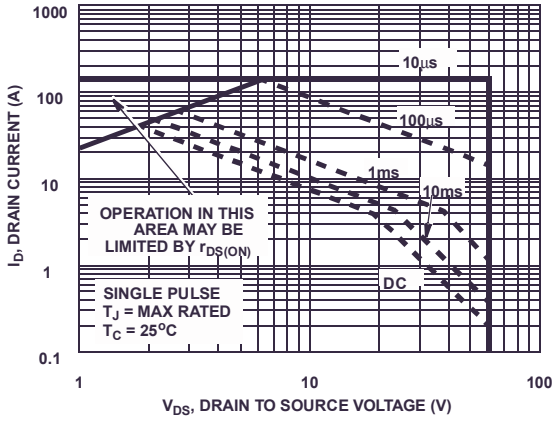
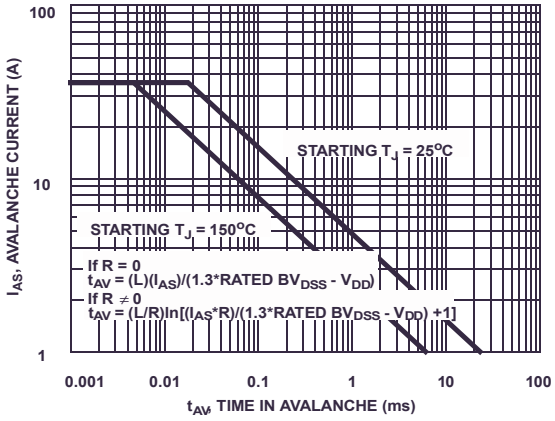


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching Capability

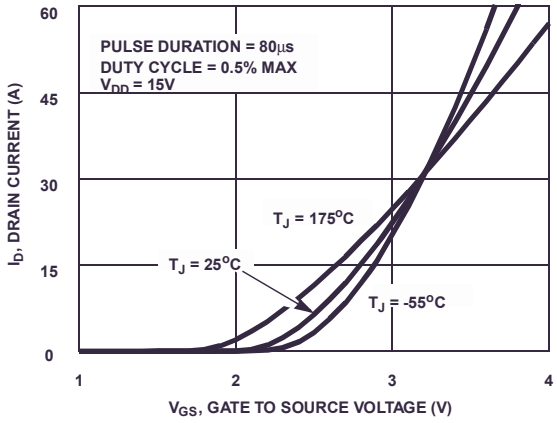


Figure 7. Transfer Characteristics

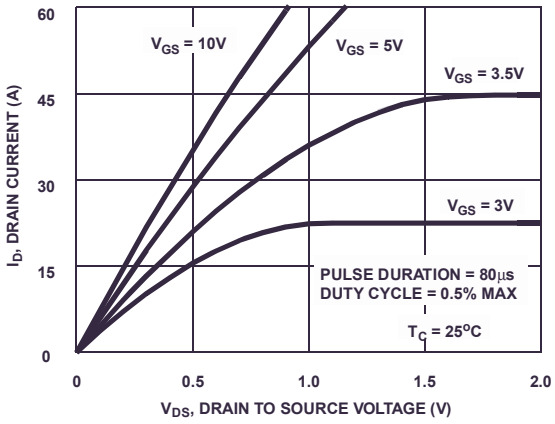


Figure 8. Saturation Characteristics

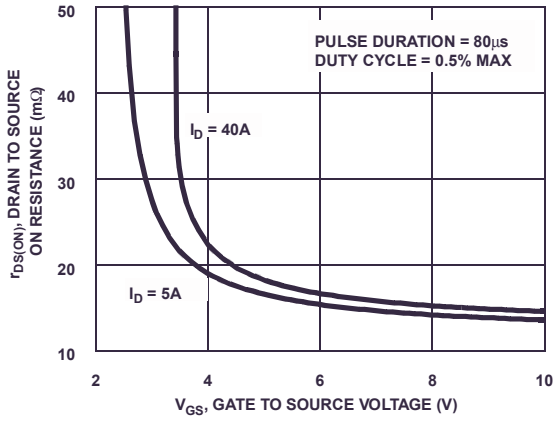


Figure 9. Drain to Source On Resistance vs Gate Voltage and Drain Current

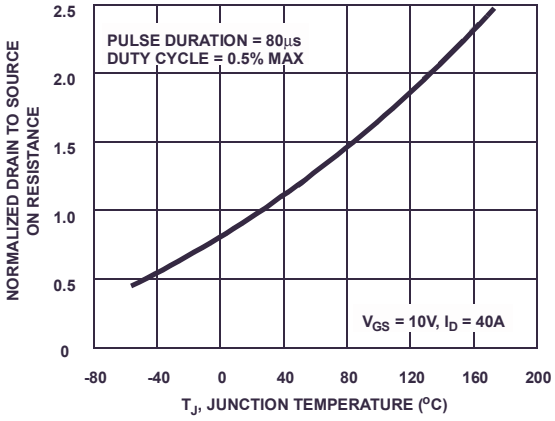


Figure 10. Normalized Drain to Source On Resistance vs Junction Temperature

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Typical Characteristics T_C = 25°C unless otherwise noted

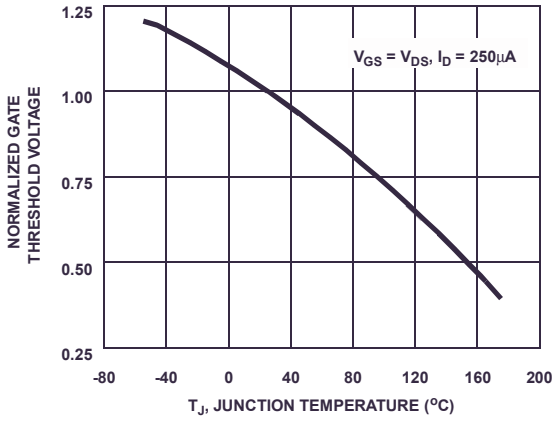


Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature

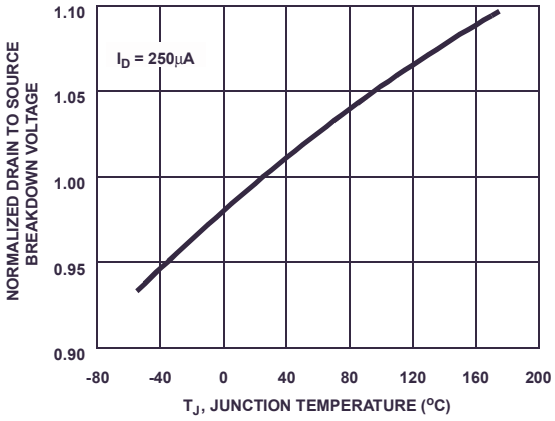


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

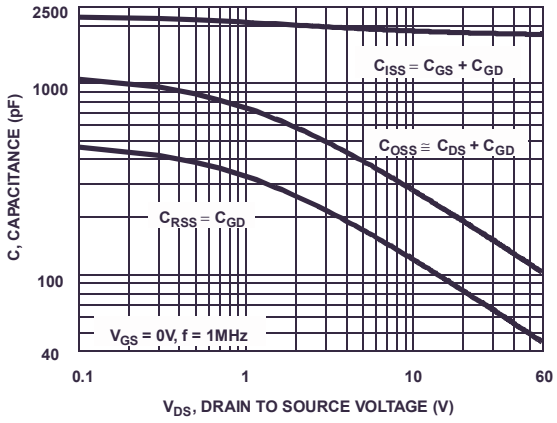


Figure 13. Capacitance vs Drain to Source Voltage

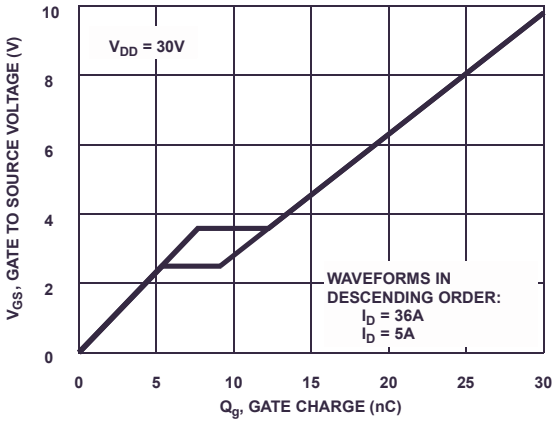


Figure 14. Gate Charge Waveforms for Constant Gate Current

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Test Circuits and Waveforms

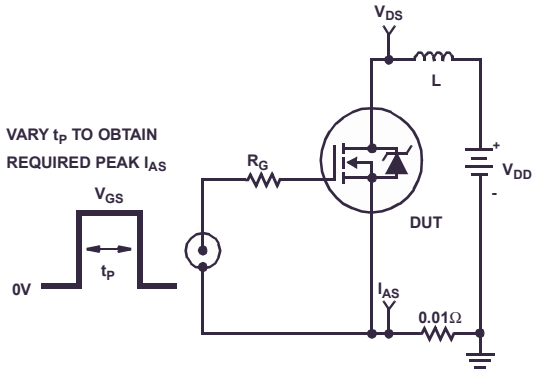


Figure 15. Unclamped Energy Test Circuit

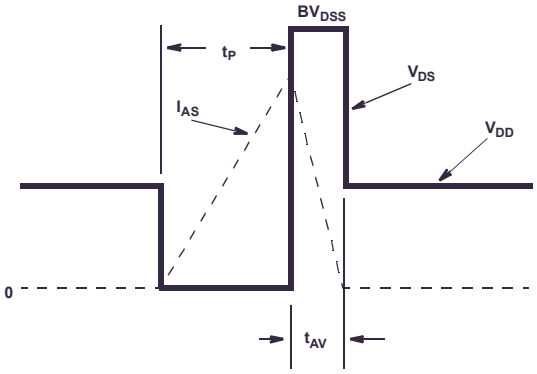


Figure 16. Unclamped Energy Waveforms

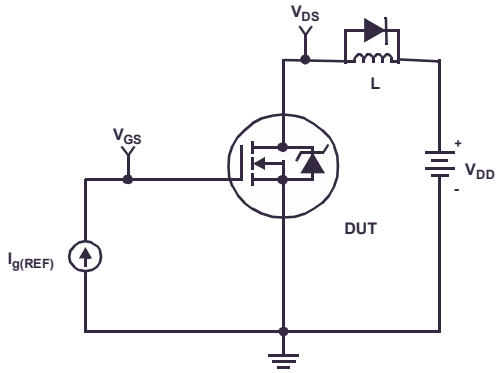


Figure 17. Gate Charge Test Circuit

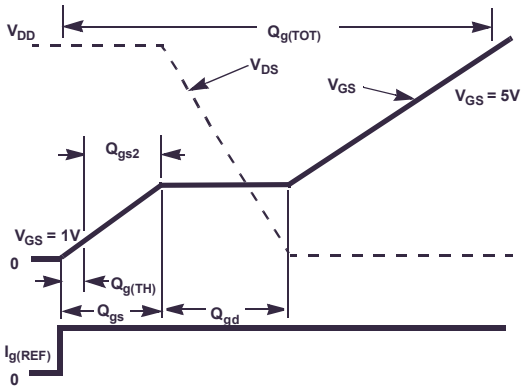


Figure 18. Gate Charge Waveforms

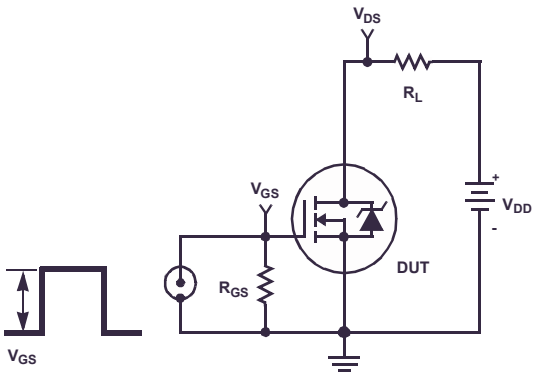


Figure 19. Switching Time Test Circuit

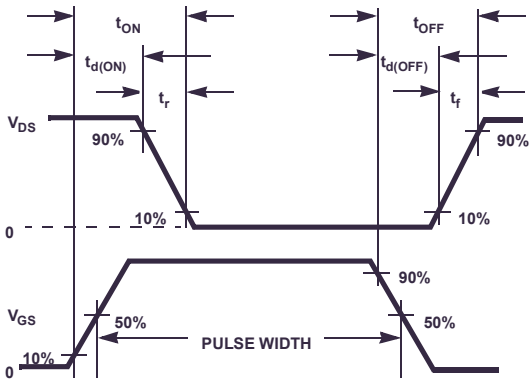


Figure 20. Switching Time Waveforms

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Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM}, and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM}, in an application. Therefore the application's ambient temperature, T_A (^oC), and thermal resistance $R_{\theta JA}$ ($^oC/W$) must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}} \quad \text{(EQ. 1)}$$

In using surface mount devices such as the TO-252 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

1. Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
2. The number of copper layers and the thickness of the board.
3. The use of external heat sinks.
4. The use of thermal vias.
5. Air flow and board orientation.
6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the $R_{\theta JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

$$R_{\theta JA} = 33.32 + \frac{23.84}{(0.268 + Area)} \quad \text{(EQ. 2)}$$

Area in Inches Squared

$$R_{\theta JA} = 33.32 + \frac{154}{(1.73 + Area)} \quad \text{(EQ. 3)}$$

Area in Centimeters Squared

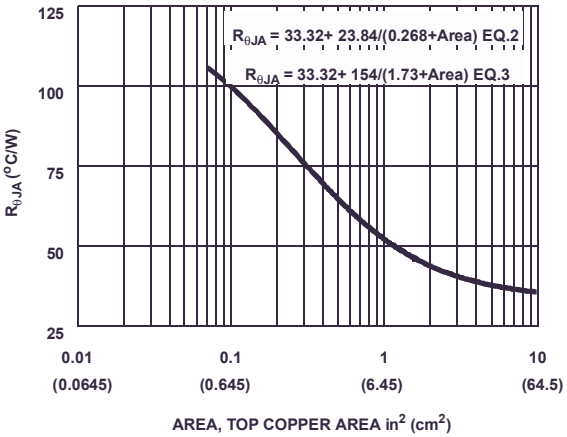


Figure 21. Thermal Resistance vs Mounting Pad Area

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Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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- Индивидуальный подход
- Гибкое ценообразование

Наша организация особенно сильна в поставках модулей, микросхем, пассивных компонентов, ксайленсах (XC), EPF, EPM и силовой электроники.

Большой выбор предлагаемой продукции, различные виды оплаты и доставки, позволят Вам сэкономить время и получить максимум выгоды от сотрудничества с нами!

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Перечень производителей, продукцию которых мы поставляем на российский рынок



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С удовольствием будем прорабатывать для Вас поставки всех необходимых компонентов по текущим запросам для скорейшего выявления групп элементов, по которым сотрудничество именно с нашей компанией будет для Вас максимально выгодным!

С уважением,

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